## IN THE U.S. PATENT AND TRADEMARK OFFICE

## INFORMATION SHEET

Applicant:

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HIRAYAMA, Hideki

Application No.:

Filed:

August 30, 2001

For:

IMPURITY DOPING METHOD FOR SEMICONDUCTOR AS WELL AS SYSTEM THEREFOR AND SEMICONDUCTOR MATERIALS PREPARED THEREBY

Priority Claimed Under 35 U.S.C. 119 and/or 120:

COUNTRY

DATE

NUMBER

Japan

09/01/00

2000-264743

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The above information is submitted to advise the USPTO of all relevant facts in connection with the present application. A timely executed Declaration in accordance with 37 CFR 1.64 will follow.

Respectfully submitted,

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/cqc

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